COMPLIANT

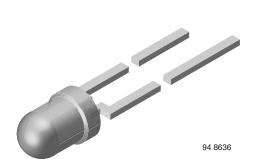
HALOGEN FREE

GREEN



# Vishay Semiconductors

# High Speed Infrared Emitting Diode, 850 nm, Surface Emitter Technology



#### **DESCRIPTION**

As part of the <u>SurfLight<sup>IM</sup></u> portfolio, the VSLY3850 is an infrared, 850 nm emitting diode based on GaAlAs surface emitter chip technology with extreme high radiant intensity, high optical power and high speed, molded in a clear, untinted T1 plastic package.

### **FEATURES**

· Package type: leaded

• Package form: T-1, clear epoxy

• Dimensions: Ø 3 mm

• Peak wavelength:  $\lambda_p = 850 \text{ nm}$ 

· High speed

High radiant power

· High radiant intensity

• Angle of half intensity:  $\phi = \pm 18^{\circ}$ 

· Suitable for high pulse current operation

• Good spectral matching with CMOS cameras

 Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>



- Infrared radiation source for operation with CMOS cameras
- High speed IR data transmission
- 3D TV application
- · Light curtains

PRODUCT SUMMARY				
COMPONENT	I <sub>e</sub> (mW/sr)	φ (deg)	λ <sub>p</sub> (nm)	t <sub>r</sub> (ns)
VSLY3850	70	± 18	850	10

#### Note

• Test conditions see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
VSLY3850	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-1	
VSLY3850-ASZ	Ammopack	MOQ: 10 000 pcs, 2000 pcs/box	T-1	

#### Note

MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V <sub>R</sub>	5	V
Forward current		I <sub>F</sub>	100	mA
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu s$	I <sub>FM</sub>	200	mA
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	1	Α
Power dissipation		P <sub>V</sub>	190	mW
Junction temperature		Tj	100	°C
Operating temperature range		T <sub>amb</sub>	-40 to +85	°C
Storage temperature range		T <sub>stg</sub>	-40 to +100	°C
Soldering temperature	t ≤ 5 s, 2 mm from case	T <sub>sd</sub>	260	°C
Thermal resistance junction / ambient	J-STD-051, leads 7 mm, soldered on PCB	$R_{thJA}$	300	K/W





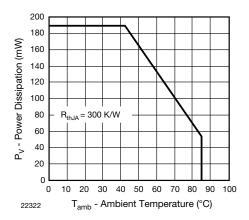


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

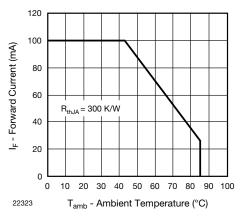


Fig. 2 - Forward Current Limit vs. Ambient Temperature

<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V <sub>F</sub>	-	1.65	1.9	V
	$I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$	V <sub>F</sub>	-	2.9	-	V
Temperature coefficient of V <sub>F</sub>	I <sub>F</sub> = 1 mA	TK <sub>VF</sub>	-	-1.45	-	mV/K
	I <sub>F</sub> = 10 mA	TK <sub>VF</sub>	-	-1.25	-	mV/K
Reverse current		I <sub>R</sub>	Not designed for reverse operation			μΑ
Junction capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz,}$ $E = 0 \text{ mW/cm}^2$	CJ	-	125	-	pF
Radiant intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l <sub>e</sub>	35	70	105	mW/sr
	$I_F = 1 \text{ A}, t_p = 100 \mu\text{s}$	I <sub>e</sub>	-	600	-	mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фе	-	55	-	mW
Temperature coefficient of radiant power	I <sub>F</sub> = 1 mA	TK <sub>φe</sub>	-	-0.35	-	%/K
Angle of half intensity		φ	-	± 18	-	deg
Peak wavelength	I <sub>F</sub> = 30 mA	λρ	840	850	870	nm
Spectral bandwidth	I <sub>F</sub> = 30 mA	Δλ	-	30	-	nm
Temperature coefficient of Ip	I <sub>F</sub> = 30 mA	$TK_{\lambdap}$	-	0.25	-	nm
Rise time	I <sub>F</sub> = 100 mA, 20 % to 80 %	t <sub>r</sub>	-	10	-	ns
Fall time	I <sub>F</sub> = 100 mA, 20 % to 80 %	t <sub>f</sub>	-	10	-	ns



## **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

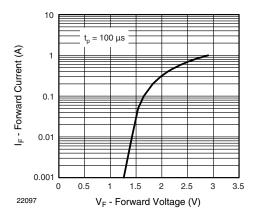


Fig. 3 - Forward Current vs. Forward Voltage

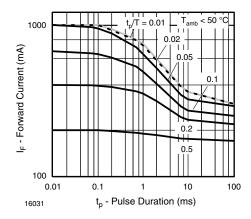


Fig. 4 - Pulse Forward Current vs. Pulse Duration

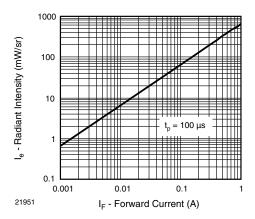


Fig. 5 - Radiant Intensity vs. Forward Current

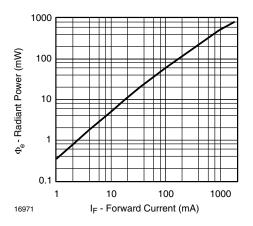


Fig. 6 - Radiant Power vs. Forward Current

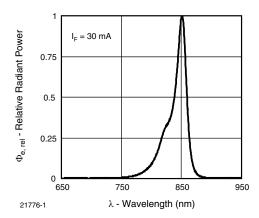


Fig. 7 - Relative Radiant Power vs. Wavelength

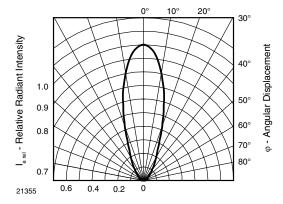


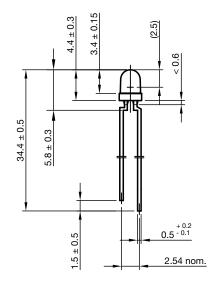
Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

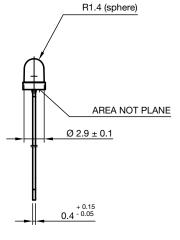


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### **PACKAGE DIMENSIONS** in millimeters







technical drawings according to DIN specifications

Drawing-No.: 6.544-5264.01-4

Issue: 4; 28.07.14



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